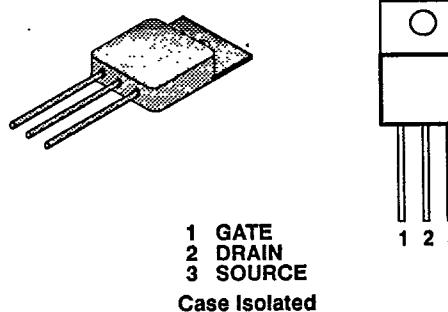


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TO-257AB
 Hermetic Package

TOP VIEW



PRODUCT SUMMARY

$V_{(BR)DSS}$ (V)	$r_{DS(ON)}$ (Ω)	I_D (A)
-200	0.50	-8.0

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ Unless Otherwise Noted)¹

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Drain-Source Voltage		V_{DS}	200	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current	$T_C = 25^\circ\text{C}$	I_D	8.0	A
	$T_C = 100^\circ\text{C}$		5.1	
Pulsed Drain Current ²		I_{DM}	32	
Power Dissipation	$T_C = 25^\circ\text{C}$	P_D	70	W
	$T_C = 100^\circ\text{C}$		27	
Operating Junction & Storage Temperature Range		T_J, T_{stg}	-55 to 150	°C
Lead Temperature ($1/16$ " from case for 10 sec.)		T_L	300	

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THERMAL RESISTANCE RATINGS¹

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Case	R_{thJC}		1.8	K/W
Junction-to-Ambient	R_{thJA}		80	
Case-to-Sink	R_{thCS}	1.0		

¹Negative signs for current and voltage ratings have been omitted for the sake of clarity.

²Pulse width limited by maximum junction temperature (refer to transient thermal impedance data, Figure 11).

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ Unless Otherwise Noted)
P-Channel DMOS Transistor Schematic Diagrams Have Been Omitted for Clarity

T-39-21

PARAMETER	SYMBOL	TEST CONDITIONS	TYP	LIMITS		UNIT
				MIN	MAX	
STATIC						
Drain-Source Breakdown Voltage	$V_{(\text{BR})DSS}$	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		200		V
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$		2.0	4.0	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 160 \text{ V}, V_{GS} = 0 \text{ V}$		25		μA
		$V_{DS} = 160 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 125^\circ\text{C}$			250	
On-State Drain Current ¹	$I_{D(\text{ON})}$	$V_{DS} = 10 \text{ V}, V_{GS} = 10 \text{ V}$		8.0		A
Drain-Source On-State Resistance ¹	$r_{DS(\text{ON})}$	$V_{GS} = 10 \text{ V}, I_D = 5.1 \text{ A}$	0.28		0.50	Ω
		$V_{GS} = 10 \text{ V}, I_D = 5.1 \text{ A}, T_J = 125^\circ\text{C}$	0.56		1.0	
Forward Transconductance ¹	g_f	$V_{DS} = 15 \text{ V}, I_D = 5.1 \text{ A}$	5.0	4.0		s
DYNAMIC						
Input Capacitance	C_{iss}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	1300			pF
Output Capacitance	C_{oss}		500			
Reverse Transfer Capacitance	C_{rss}		250			
Total Gate Charge ²	Q_g	$V_{DS} = 0.5 \times V_{(\text{BR})DSS}, V_{GS} = 10 \text{ V}, I_D = 8 \text{ A}$	55	30	90	nC
Gate-Source Charge ²	Q_{gs}		10	5.0	15	
Gate-Drain Charge ²	Q_{gd}		30	10	50	
Turn-On Delay Time ²	$t_{d(on)}$	$V_{DD} = 100 \text{ V}, R_L = 12.5 \Omega$ $I_D \approx 8 \text{ A}, V_{GEN} = 10 \text{ V}, R_G = 4.7 \Omega$	10		30	ns
Rise Time ²	t_r		45		80	
Turn-Off Delay Time ²	$t_{d(off)}$		40		80	
Fall Time ²	t_f		40		60	
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS						
Continuous Current	I_S				8.0	A
Pulsed Current ³	I_{SM}				32	
Forward Voltage ¹	V_{SD}	$I_F = I_S, V_{GS} = 0 \text{ V}$			2.6	V
Reverse Recovery Time	t_{rr}	$I_F = I_S, dI_F/dt = 100 \text{ A}/\mu\text{s}$	200			ns
Reverse Recovery Charge	Q_{rr}			1.0		μC

¹Pulse test: Pulse Width $\leq 300 \mu\text{sec}$, Duty Cycle $\leq 2\%$.

²Independent of operating temperature.

³Pulse width limited by maximum junction temperature (refer to transient thermal impedance data, Figure 11).

TYPE 2N7092 (TO-220) 25°C Unless Otherwise Specified

Figure 1. Output Characteristics

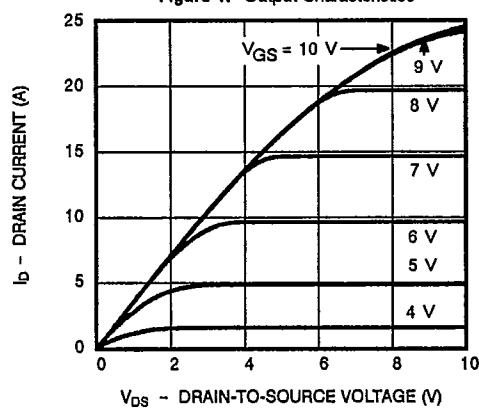


Figure 2. Transfer Characteristics

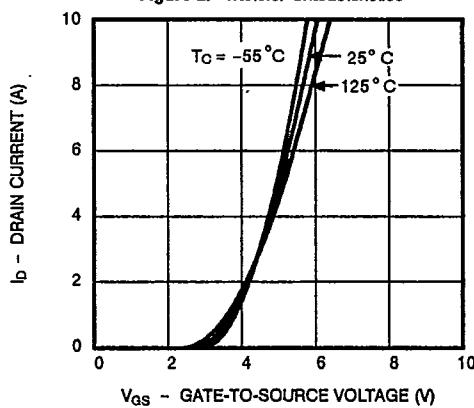


Figure 3. Transconductance

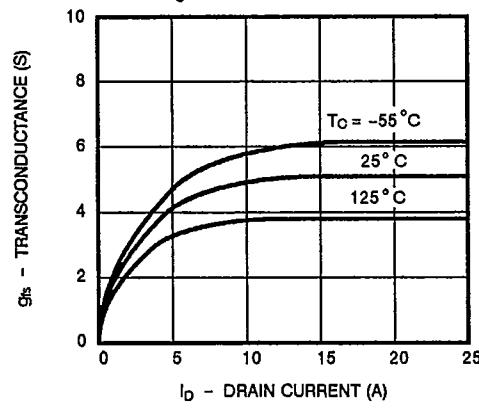
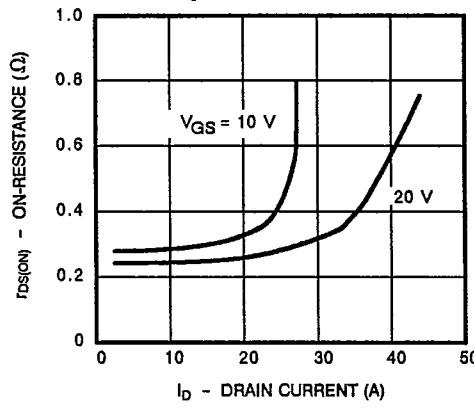


Figure 4. On-Resistance



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Figure 5. Capacitance

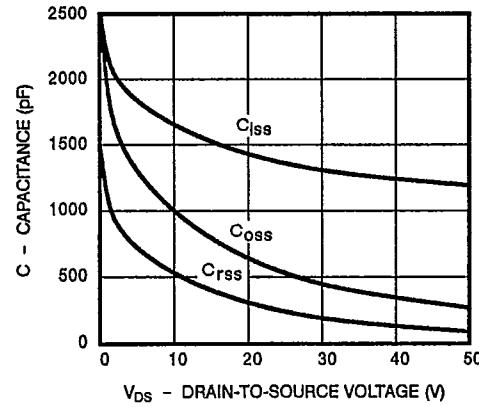
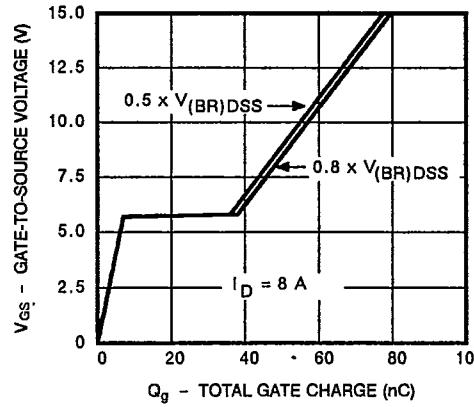


Figure 6. Gate Charge



TYPICAL CHARACTERISTICS (Cont'd)

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Figure 7. On-Resistance vs. Junction Temperature

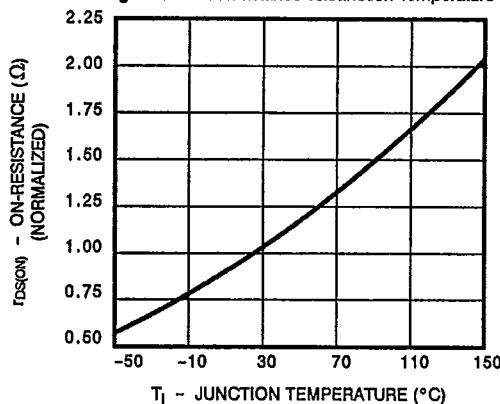
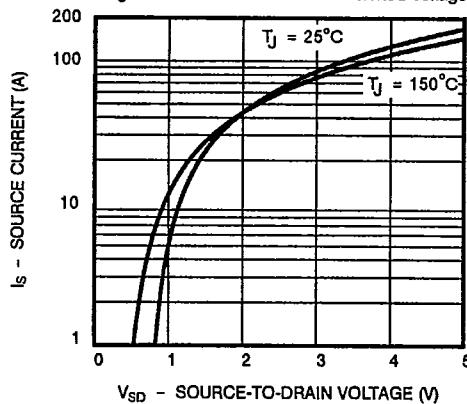


Figure 8. Source-Drain Diode Forward Voltage



THERMAL RATINGS

Figure 9. Maximum Drain Current vs. Case Temperature

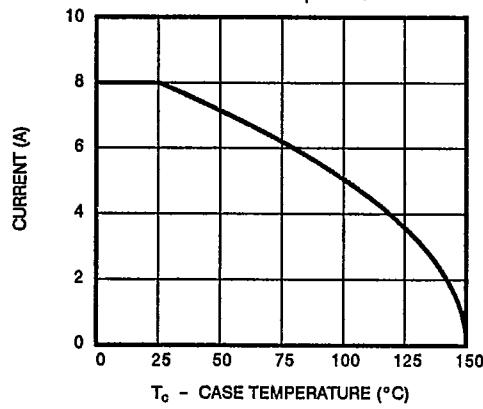


Figure 10. Safe Operating Area

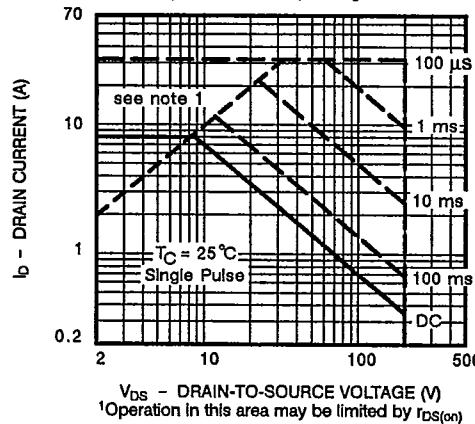


Figure 11. Normalized Effective Transient Thermal Impedance, Junction-to-Case

